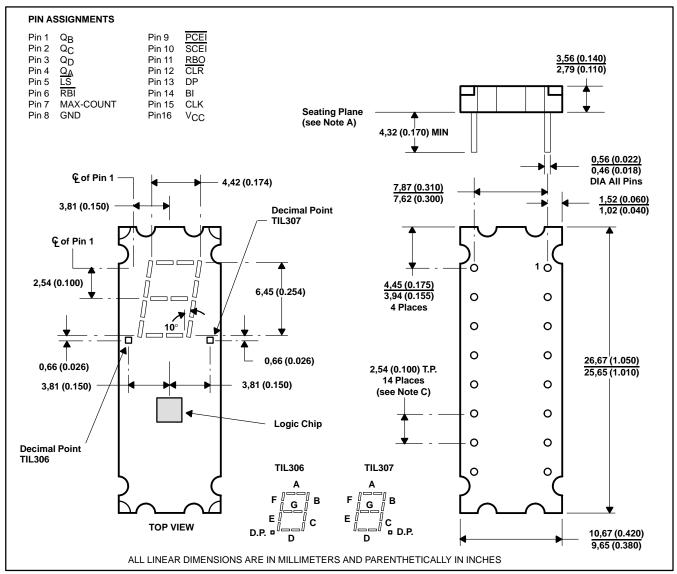
SOLID-STATE DISPLAYS WITH INTEGRAL TTL MSI CIRCUIT CHIP FOR USE IN ALL SYSTEMS WHERE THE DATA TO BE DISPLAYED IS THE PULSE COUNT

- 6,9-mm (0.270-Inch) Character Height
- High Luminous Intensity
- TIL306 Has Left Decimal
- TIL307 Has Right Decimal
- Easy System Interface

- Wide Viewing Angle
- Internal TTL MSI Chip and Counter, Latch, Decoder, and Driver
- Constant-Current Drive for Light-Emitting Diodes

mechanical data

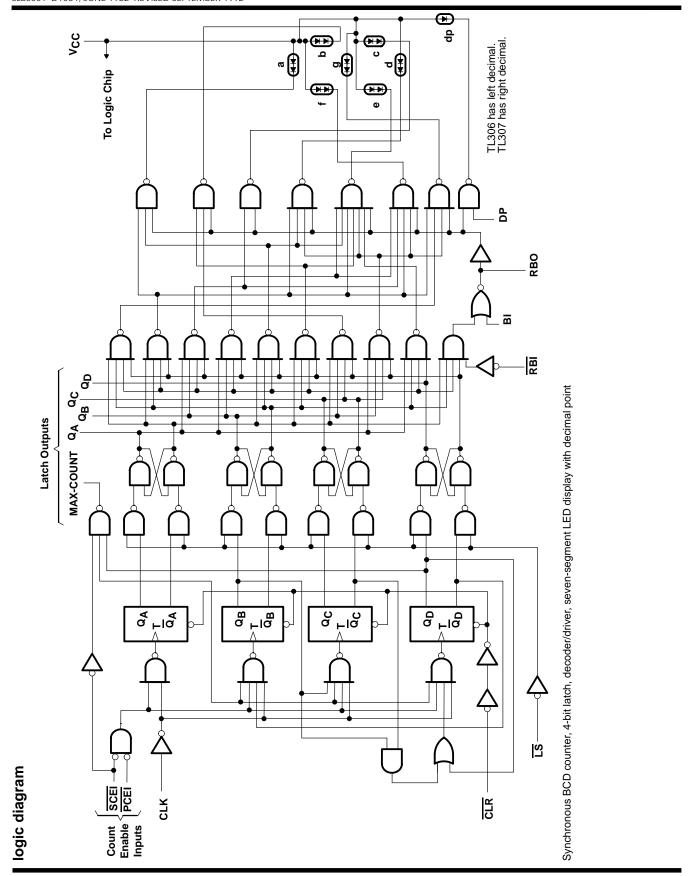
These assemblies consist of display chips and a TTL MSI chip mounted on a header with a red molded plastic body. Multiple displays may be mounted on 11,43-mm (0.450-inch) centers.



NOTES: A. Lead dimensions are not controlled above the seating plane.

- B. Centerlines of character segments and decimal points are shown as dashed lines. Associated dimensions are nominal.
- C. The true-position pin spacing is 2,54 mm (0.100 inch) between centerlines. Each centerline is located with 0,26 mm (0.010 inch) of its true longitudinal position relative to pins 1 and 16.





description

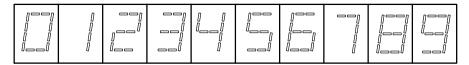
These internally-driven seven-segment light-emitting-diode (LED) displays contain a BCD counter, a four-bit latch, and a decoder/LED driver in a single 16-pin package. A description of the functions of the inputs and outputs of these devices are in the terminal function table.

The TTL MSI circuits contain the equivalent of 86 gates on a single chip. Logic inputs and outputs are completely TTL/DTL compatible. The buffered inputs are implemented with relatively large resistors in series with the bases of the input transistors to lower drive-current requirements to one-half of that required for a standard Series 54/74 TTL input. The serial-carry input, actually two internal loads, is rated as one standard series 54/74 load.

The logic outputs, except RBO, are active pullup, and the latch outputs Q_A , Q_B , Q_C , and Q_D are each capable of driving three standard Series 54/74 loads at a low logic level or six loads at a high logic level while the maximum-count output is capable of driving five Series 54/74 loads at a low logic level or ten loads at a high logic level. The RBO node with passive pull-up serves as a ripple-blanking output with the capability to drive three Series 54/74 loads.

The LED driver outputs are designed specifically to maintain a relatively constant on-level current of approximately 7 mA through each LED segment and decimal point. All inputs are diode clamped to minimize transmission-line effects, thereby simplifying system design. Maximum clock frequency is typically 18 MHz and power dissipation is typically 600 mW with all segments on.

The display format is as follows:



The displays may be interconnected to produce an n-digit display with the following features:

- Ripple-blanking input and output for blanking leading or trailing zeroes
- Floating-decimal-point logic capability
- Overriding blanking for suppressing entire display or pulse modulation of LED brightness
- Dual count-enable inputs for parallel lookahead and serial ripple logic to build high-speed fully synchronous, multidigit counter systems with no external logic, minimizing total propagation delay from the clock to the last latch output
- Provision for ripple-count cascading between packages
- Positive-edge-triggered synchronous BCD counter
- Parallel BCD data outputs available to drive logic processors or remote slaved displays simultaneously with data being displayed
- Latch strobe input allows counter to operate while a previous data point is displayed
- Reset-to-zero capability with clear input.



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Terminal Functions

PIN					
NAME	NO.	DESCRIPTION			
BLANKING Input (BI)	14	When high, will blank (turn off) the entire display and force RBO low. Must be low for normal display. May be pulsed to implement intensity control of the display.			
CLEAR Input (CLR)	12	When low, resets and holds counter at 0. Must be high for normal counting.			
CLOCK Input (CLK)	15	Each positive-going transition will increment the counter provided that the circuit is in the normal counting mode (serial and parallel count enable inputs low, clear input high).			
DECIMAL POINT Input (DP)	13	Must be high to display decimal point. The decimal point is not displayed when this input is low or when the display is blanked.			
LATCH Outputs (Q _A , Q _B , Q _C , Q _D)	4, 1, 2, 3	The BCD data that drives the decoder can be stored in the 4-bit latch and is available at these outputs for driving other logic and/or processors. The binary weights of the outputs are: $Q_A = 1$, $Q_B = 2$, $Q_C = 4$, $Q_D = 8$.			
LATCH STROBE Input (LS)	5	When low, data in latches follow the data in the counter. When high, the data in the latches are held constant, and the counter may be operated independently.			
MAX-COUNT Output	7	Will go low when the counter is at 9 and serial count enable input is low. Will return high when the counter changes to 0 and will remain high during counts 1 through 8. Will remain high (inhibited) as long as serial count enable input is high.			
PARALLEL Count Enable Input (PCEI)	9	Must be low for normal counting mode. When high, counter will be inhibited. Logic level must not be changed when the clock is low.			
RIPPLE-BLANKING Input (RBI)	6	When the data in the latches is BCD 0, a low input will blank the entire display and force the RBO low. This input has no effect if the data in the latches is other than 0.			
RIPPLE-BLANKING Output (RBO)	11	Supplies ripple-blanking information for the ripple-blanking input of the next decade. Provides a low if BI is high, or if RBI is low and the data in the latches is BCD 0; otherwise, this output is high. This pin has a resistive pullup circuit suitable for performing a wire-AND function with any open-collector output. Whenever this pin is low, the entire display will be blanked; therefore, this pin may be used as an active-low blanking input.			
SERIAL Count Enable Input (SCEI)	10	Must be low for normal counting mode, also must be low to enable maximum count output to go low. When high, counter will be inhibited and maximum count output will be driven high. Logic level must not be changed when the clock is low.			

absolute maximum ratings over operating case temperature range (unless otherwise noted)

Supply voltage, V _{CC} (see Note 1):	Continuous	5.5 V
	Nonrepetitive peak, $t_w \le 100 \text{ ms}$	7 V
Input voltage (see Note 1)		5.5 V
Operating case temperature range	e, T _C (see Note 2) 0°C t	o 85°C
Storage temperature range		o 85°C

NOTES: 1. Voltage values are with respect to network ground terminal.

2. Case temperature is the surface temperature of the plastic measured directly over the integrated circuit. Forced-air cooling may be required to maintain this temperature.



recommended operating conditions

			MIN	NOM	MAX	UNIT	
Supply voltage, V _{CC}			4.75	5	5.25	V	
	Low logic level	Q _A , Q _B , Q _C , Q _D , RBO			3		
		MAX-COUNT Output			5		
Normalilzed fan-out from each output, N (to Series 54/74 integrated circuits)	High logic level	RBO			3		
(to Series 34/74 integrated circuits)		Q _A , Q _B , Q _C , Q _D			6		
		MAX-COUNT Output			10		
Olaska makasa sharatika a s	•	High logic level	25				
Clock pulse duration, tw(clock)		Low logic level	55			ns	
Clear pulse duration, t _{W(clear)}			25			ns	
Latch strobe pulse duration, t _w (latch strobe)			45			ns	
·	PCEI/SCEI↑ before CLOCK↑		30				
Setup time, t _{SU}	CLEAR [↑] before	CLEAR↑ before CLOCK↑				ns	
Operating case temperature, T _C			0		70	°C	

electrical characteristics at 25°C case temperature

PARAMETER		TEST CO	NDITIONS	MIN	TYP [†]	MAX	UNIT	
VIH	High-level input voltage				2			V
V _{IL}	Low-level input voltage						0.8	V
VIK	Input clamp voltage		$V_{CC} = 4.75 V$,	$I_{I} = -12 \text{ mA}$			-1.5	V
Vон		RBO	$V_{CC} = 4.75 \text{ V},$	I _{OH} = -120 μA				
	High-level output voltage	Q _A , Q _B , Q _C , Q _D	$V_{CC} = 4.75 V$,	I _{OH} = -240 μA	2.4			V
		MAX-COUNT Output	$V_{CC} = 4.75 V$,	$I_{OH} = -400 \mu A$				
V	Low-level output voltage	Q _A , Q _B , Q _C , Q _D , RBO	V _{CC} = 4.75 V,	I _{OL} = 4.8 mA				V
VOL	(see Note 3)	MAX-COUNT Output	V _{CC} = 4.75 V,	I _{OL} = 8 mA			0.4	
IĮ	Input current at maximum input voltage		V _{CC} = 5.25 V,	V _I = 5.5 V			1	mA
	High-level input current	SCEI		V _I = 2.4 V			40	μΑ
lн		RBO node	V _{CC} = 5.25 V,		-0.12	-0.5		mA
		Other inputs					20	μΑ
	Low-level input current	SCEI		V _I = 0.4 V			-1.6	
Ι _Ι L		RBO node	V _{CC} = 5.25 V,			-1.5	-2.4	mA
		Other inputs					-0.8	
1	Short-circuit output current	Q _A , Q _B , Q _C , Q _D	V 505 V		-9		-27.5	A
los		MAX-COUNT Output	$V_{CC} = 5.25 \text{ V}$		-15		-55	mA
Icc	Supply current		V _{CC} = 5.25 V,	See Note 4		120	200	mA
	Luminous intensity (see Note 5)	Figure ∄	V 5 V		700	1200		μcd
I _V		DP Input	V _{CC} = 5 V		40	70		μcd
λρ	λ _p Wavelength at peak emission		V _{CC} = 5 V,	See Note 4		660		nm
Δλ			V _{CC} = 5 V,	See Note 4		20		nm

[†] All typical values are at $V_{CC} = 5 \text{ V}$.

NOTES: 3. This parameter is measured with the display blanked (BI = 5 V).

- 4. These parameters are measured with all LED segments and the decimal point on.
- 5. Luminous intensity is measured with a light sensor and filter combination that approximates the CIE (International Commission on Illumination) eye-response curve.

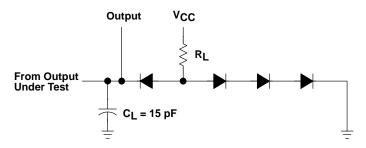


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switching characteristics, $V_{CC} = 5 \text{ V}$, $T_C = 25^{\circ}\text{C}$

PARAMETER†	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	MIN	TYP	MAX	UNIT
fmax				12	18		MHz
^t PLH	SERIAL lookahead	MAX-COUNT Output			12		ns
t _{PHL}			$C_L = 15 \text{ pF}, R_L = 560 \Omega,$		23		
t _{PLH}	CLK Input	MAX-COUNT Output	See Figure 1		26		ns
t _{PHL}					29		
t _{PLH}	Cl K lanut	Q _A , Q _B , Q _C , Q _D	$C_L = 15 \text{ pF}, R_L = 1.2 \text{ k}\Omega,$ See Figure 1		28		ns
t _{PHL}	CLK Input				38		115
t _{PHL}	CLR Input	Q_A, Q_B, Q_C, Q_D			57		ns

PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

B. All diodes are 1N3064.

Figure 1. Load Circuit

[†] f_{max} = Maximum clock frequency tp_{LH} = Propagation delay time, low-to-high-level output

 $t_{PHL} \equiv Propagation delay time, high-to-low-level output$

TYPICAL CHARACTERISTICS

RELATIVE SPECTRAL CHARACTERISTICS V_{CC} = 5 V 0.9 T_C = 25°C 8.0 Relative Luminous Intensity 0.7 0.6 0.5 0.4 0.3 0.2 0.1 0 620 680 600 640 660 700 λ – Wavelength – nm



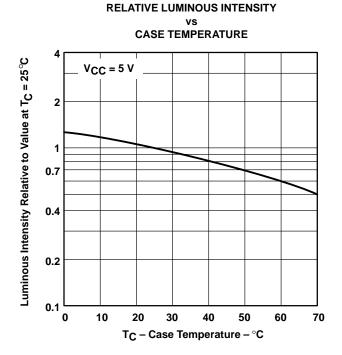


Figure 3

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